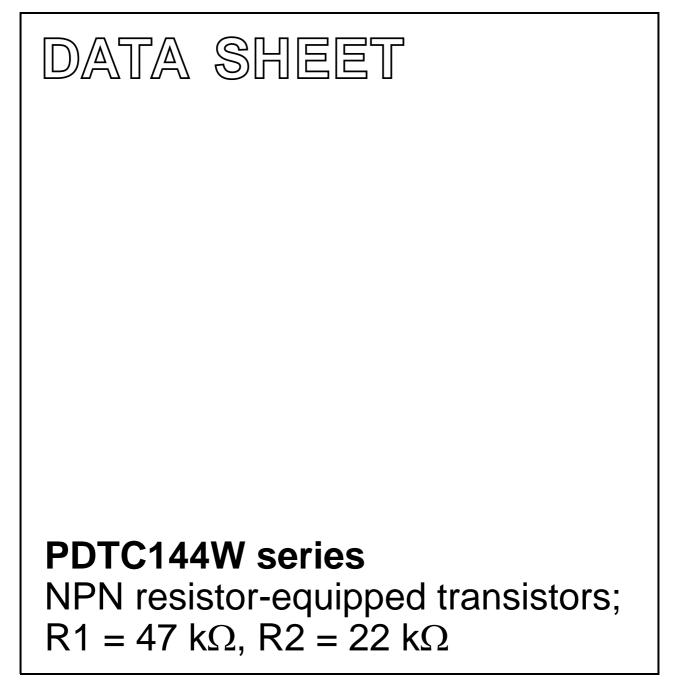
DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2004 Mar 23 2004 Aug 17



PDTC144W series

FEATURES

- · Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

PRODUCT OVERVIEW

QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V _{CEO}	collector-emitter voltage	-	50	V
lo	output current (DC)	-	100	mA
R1	bias resistor	47	-	kΩ
R2	bias resistor	22	_	kΩ

DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

TYPE NUMBER	PACKAGE		MARKING CODE	PNP COMPLEMENT	
ITPE NUMBER	PHILIPS	EIAJ	MARKING CODE	PNP COMPLEMENT	
PDTC144WE	SOT416	SC-75	42	PDTA144WE	
PDTC144WEF	SOT490	SC-89	34	PDTA144WEF	
PDTC144WK	SOT346	SC-59	41	PDTA144WK	
PDTC144WM	SOT883	SC-101	DD	PDTA144WM	
PDTC144WS	SOT54 (TO-92)	SC-43	TC144W	PDTA144WS	
PDTC144WT	SOT23	_	*20 ⁽¹⁾	PDTA144WT	
PDTC144WU	SOT323	SC-70	*20 ⁽¹⁾	PDTA144WU	

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

PDTC144W series

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTC144WS	$\begin{bmatrix} 1 \\ \vdots 2 \\ \vdots 3 \end{bmatrix}$ $\begin{bmatrix} 1 \\ \vdots \\ R^2 \\ MAM364 \end{bmatrix}$	PIN 1 2 3	base collector emitter		
PDTC144WE PDTC144WEF PDTC144WK PDTC144WT PDTC144WU	$\begin{array}{c} \hline 3 \\ \hline 1 \\ \hline 1 \\ \hline 1 \\ \hline 2 \\ \hline 7 \text{op view}} \end{array} \qquad \begin{array}{c} 1 \\ \hline R1 \\ \hline R2 \\ \hline R2 \\ \hline MDB269 \\ \hline MDB269 \\ \end{array}$	1 2 3	base emitter collector		
PDTC144WM	2 1 bottom view MHC506	1 2 3	base emitter collector		

PDTC144W series

ORDERING INFORMATION

	PACKAGE			
TYPE NUMBER	NAME	DESCRIPTION	VERSION	
PDTC144WE	_	 plastic surface mounted package; 3 leads 		
PDTC144WEF	_	 plastic surface mounted package; 3 leads SC 		
PDTC144WK	_	 plastic surface mounted package; 3 leads SOT 		
PDTC144WM	_	leadless ultra small plastic package; 3 solder lands; body $1.0 \times 0.6 \times 0.5$ mm		
PDTC144WS	_	 plastic single-ended leaded (through hole) package; 3 leads 		
PDTC144WT	 plastic surface mounted package; 3 leads 		SOT23	
PDTC144WU	_	- plastic surface mounted package; 3 leads SOT3		

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base	-	50	V
V _{EBO}	emitter-base voltage	open collector	-	10	V
Vi	input voltage				
	positive		-	+40	V
	negative		-	-10	V
lo	output current (DC)		-	100	mA
I _{CM}	peak collector current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	-	250	mW
	SOT323	note 1	_	200	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
	SOT416	note 1	-	150	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

PDTC144W series

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W
	SOT416	note 1	833	K/W

Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 μ m copper strip line.

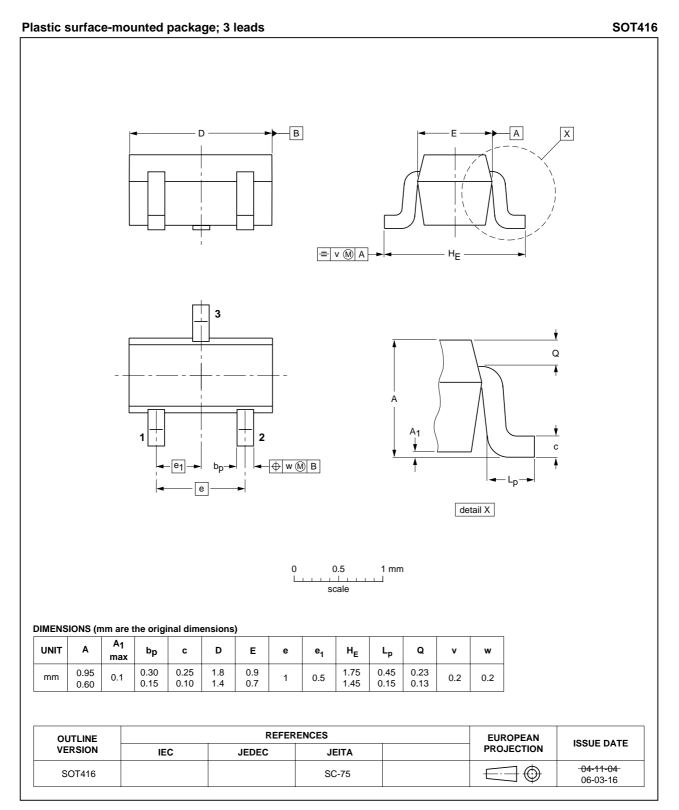
CHARACTERISTICS

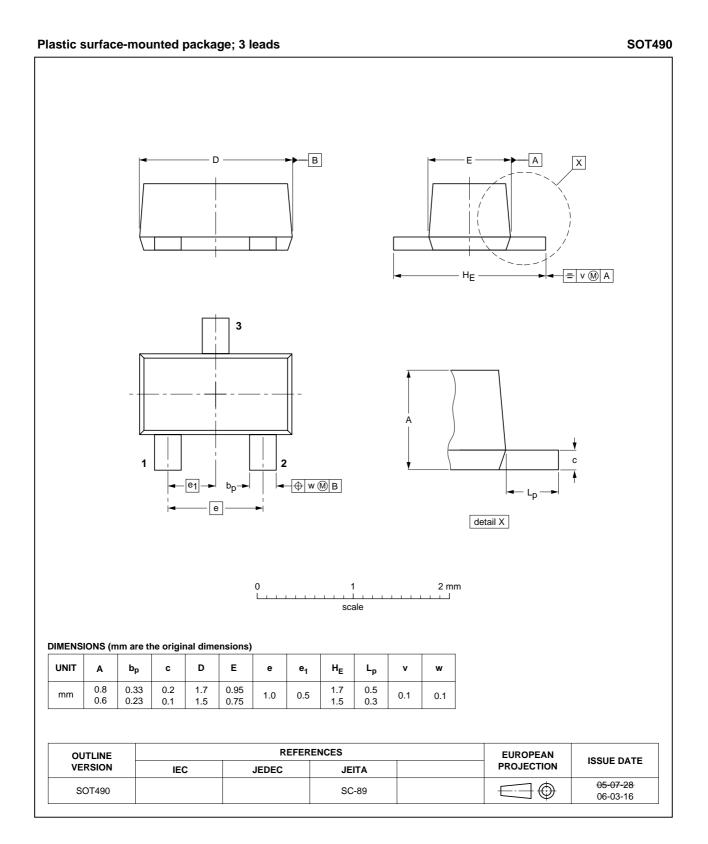
 T_{amb} = 25 °C unless otherwise specified.

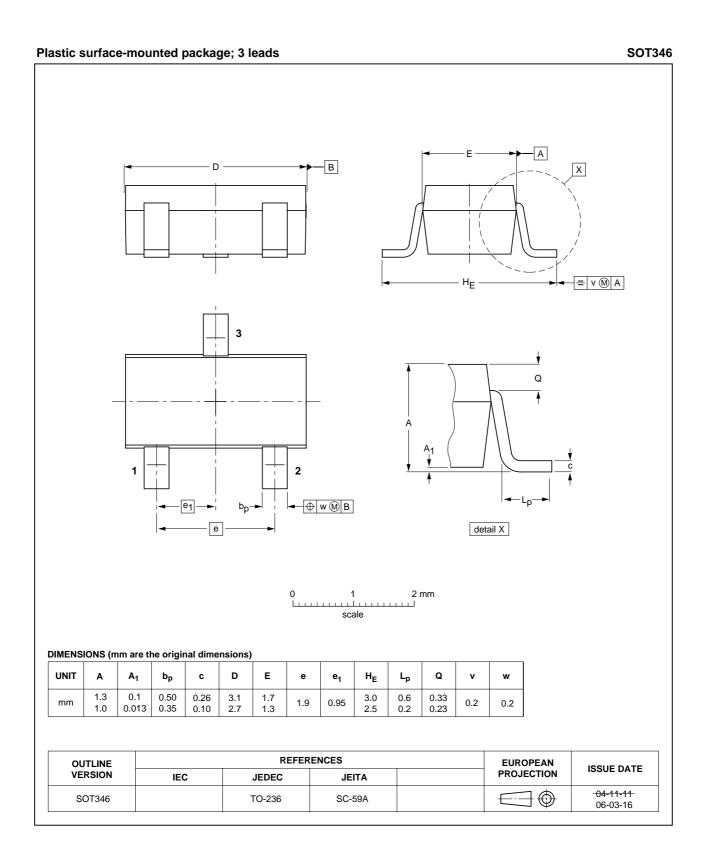
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	_	100	nA
I _{CEO}	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	_	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	_	50	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A	-	_	110	μA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$	60	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C}$ = 10 mA; $I_{\rm B}$ = 0.5 mA	-	_	150	mV
V _{i(off)}	input-off voltage	$I_{C} = 100 \ \mu A; V_{CE} = 5 \ V$	_	1.7	1.2	V
V _{i(on)}	input-on voltage	$I_{C} = 2 \text{ mA}; V_{CE} = 0.3 \text{ V}$	4	2.7	_	V
R1	input resistor		33	47	61	kΩ
<u>R2</u> R1	resistor ratio		0.37	0.47	0.57	
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	-	-	2.5	pF

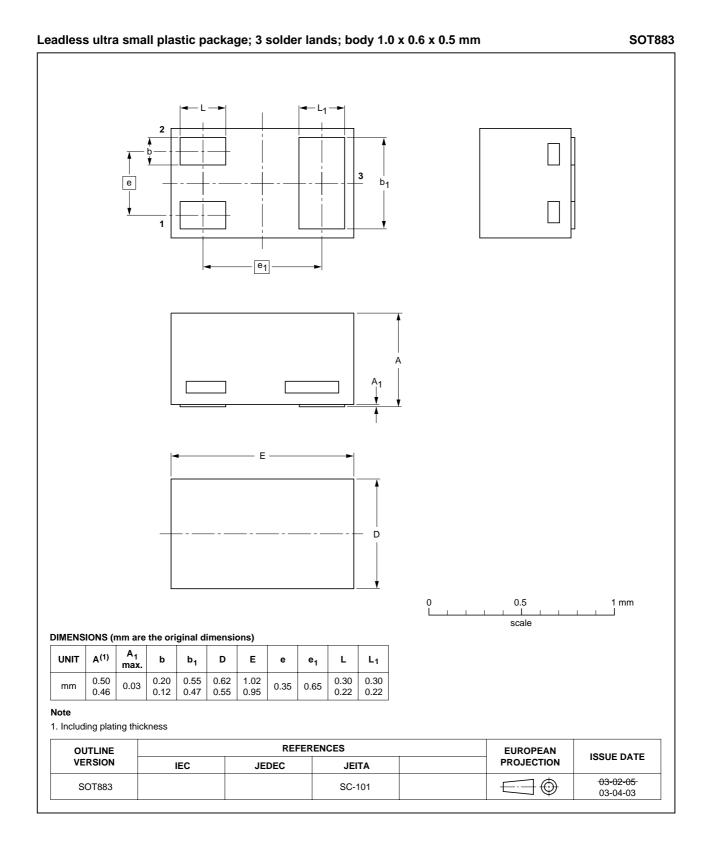
PDTC144W series

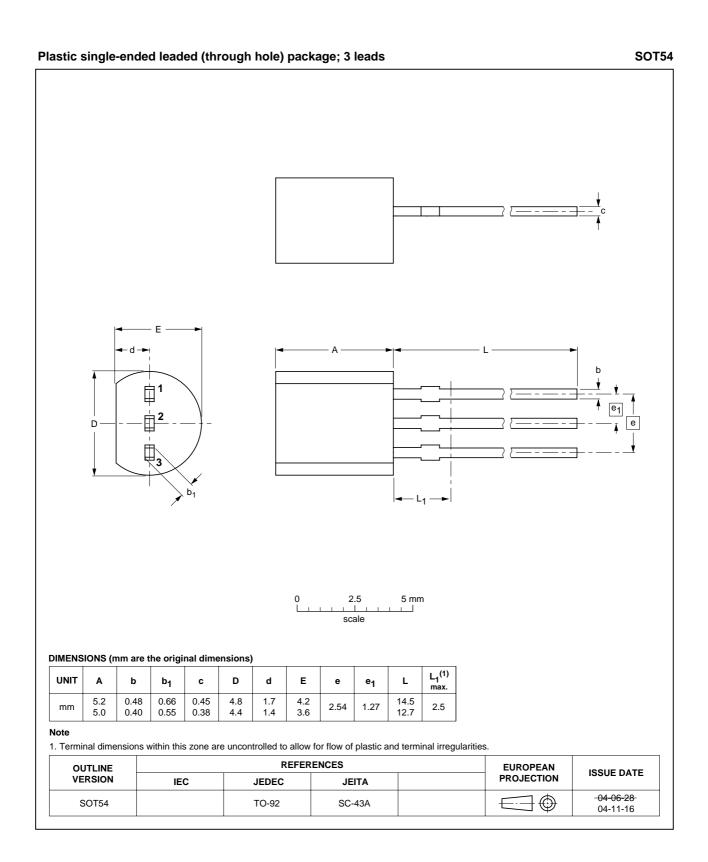
PACKAGE OUTLINES

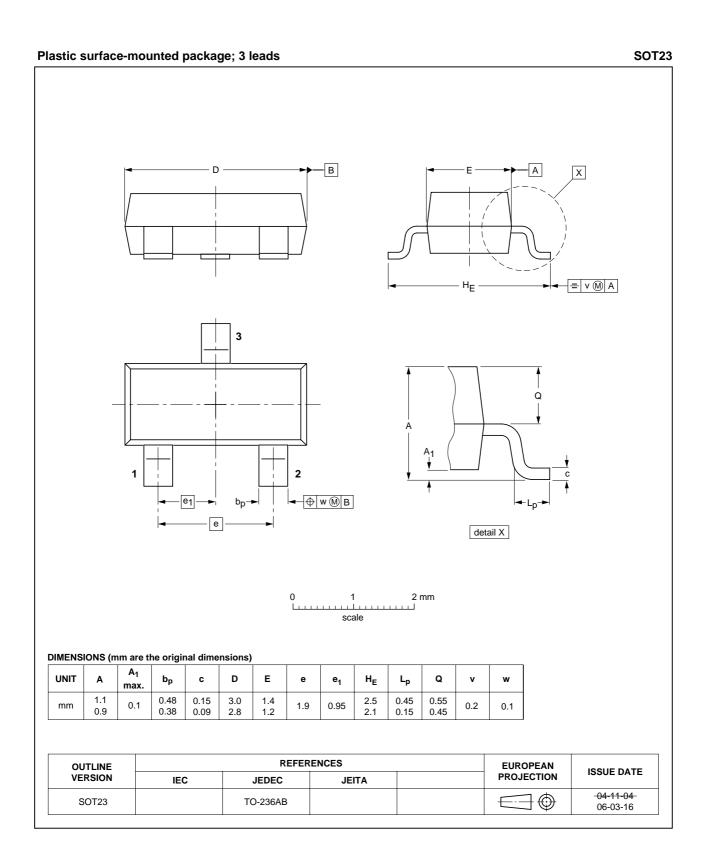


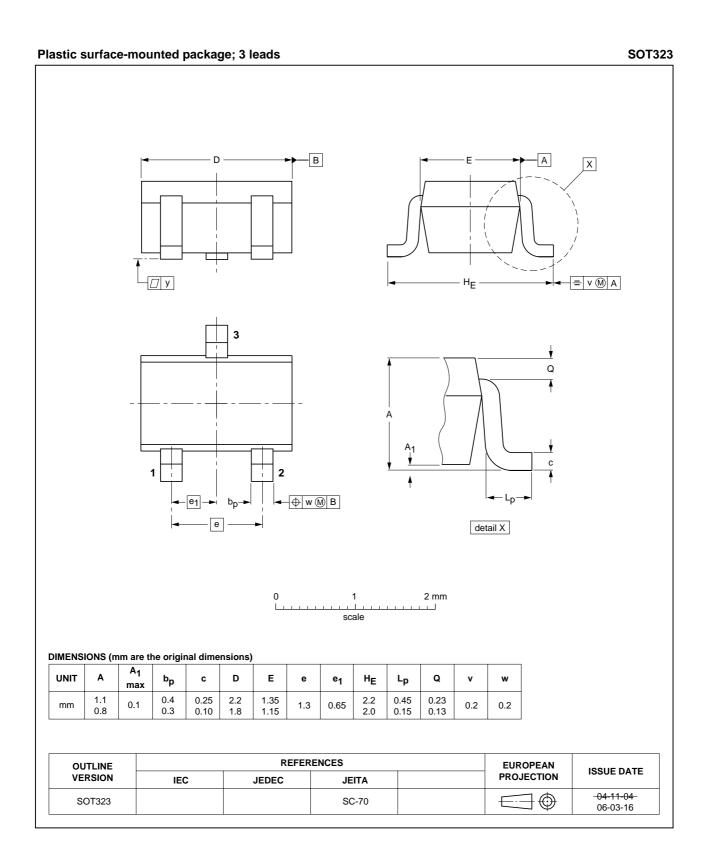












PDTC144W series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

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- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Customer notification

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Contact information

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